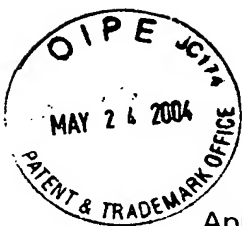


IPW



500.38899VX3

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Naoki YAMAMOTO
Serial No.: 10/787,436
Filed: February 27, 2004
For: **METHOD OF MANUFACTURING A DUAL GATE
SEMICONDUCTOR DEVICE WITH A POLY-METAL
ELECTRODE**
Group: 2812
Examiner: Jack S. J. Chen (expected)

THIRD PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

May 24, 2004

Sir:

Prior to initial examination on the merits, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Remarks begin on page 3 of this paper.